

Study of the Effect of laser Pulses on Synthesis of SnO₂ Nanoparticles by Laser Ablation in Methanol

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ABSTRACT

SnO₂ nanoparticles were prepared by laser ablation of tin in methanol at room temperature. The particles were characterized by means of TEM, AFM, FTIR, UV-Visible absorption spectrum and electrical properties. AFM micrographs show that the obtained material is spherical nanoparticles, the size and size distribution of which depends on the experimental conditions.

From FTIR spectrum show the peak absorption of SnO₂NP suspension at 657 cm⁻¹.

It is found that the band gap energy of SnO₂NPs is higher than that of bulk SnO₂ due to the decreases in the particle size according to the quantum confinement model.

From the *J-V* characteristics Al/SnO₂ NPs/c-Si/Al heterojunction the values of ideality factor for these devices is greater than unity which can be attributed to the recombination of electrons and holes in the depletion region as well as the tunneling effect depending on both sides of the heterojunction and on the presence of defect states.

Keywords: SnO₂ nanoparticles; Laser ablation; morphology; energy gap; heterojunction.

دراسة تأثير عدد النبضات على تحضير دقائق SnO₂ النانوية بالتشظية بالليزر في الميثانول

الخلاصة

تم تحضير دقائق SnO₂ النانوية بتقنية التشظية بالليزر في الميثانول في درجة حرارة الغرفة. تم تشخيص الدقائق بواسطة المجهر الإلكتروني النافذ (TEM) ومجهر القوى الذري (AFM) ومطياف تحت الحمراء (FTIR) وطيف الامتصاص الأشعة فوق البنفسجية والمرئية والخواص الكهربائية. يظهر المجهر الإلكتروني النافذ (TEM) لتوصيف شكل وحجم دقائق ثنائي أكسيد القصدير النانوية حيث اظهرت معدل قطر يتراوح من 17 الى 37 نانومتر في محلول الميثانول ذو شكل كروي منتظم وكذلك اظهرت نتائج مجهر القوى الذري (AFM) ان الدقائق التي تم الحصول عليها هي دقائق نانوية كروية. ظهر من مطياف الأشعة تحت الحمراء (FTIR) ان قمة امتصاص عوالمق دقائق SnO₂ النانوية عند 657 cm⁻¹.

وجد ان فجوة حزمة الطاقة لدقائق SnO₂ النانوية اكبر من SnO₂ في حالتها الحجمية يرجع ذلك الى انخفاض حجم الدقائق وفقا لنموذج الحصر الكمي. من خصائص *J-V* للمفروق الهجين Al/SnO₂NPs/c-Si/Al ان قيم عامل المثالية لهذه النبيلة هو اكبر من الواحد التي يمكن ان تعزى الى اعادة اتحاد الكترولون - فجوة في منطقة النضوب فضلا عن تأثير التنقيق اعتمادا على كلا الجانبين للمفروق الهجين وعلى وجود مستويات العيوب.

INTRODUCTION

Since the shape, size, and dimensionality of semiconductors are vital parameters for their properties, developing a facile method to prepare important nanomaterials with well-defined structures is of great interest and importance. Crystalline tin oxide, cassiterite structure, is a wide band gap semiconductor (~3.6 eV), It has been widely used for various catalytic applications, gas sensing, transparent conducting electrodes and liquid crystal displays, etc. [1-5].

Laser ablation is a “top-down” approach to fabricate nanoparticles where the bulk crystals were broken down to smaller particles by an intense laser beam. Pulse laser ablation in liquid emerged as a reliable alternative to conventional chemical reduction methods for fabricating oxide and noble metal particles [6].

Pulse laser ablation of a solid target in liquid media is becoming an increasingly popular approach for controlled synthesis of noble metal and metal oxide nanoparticles. It is a chemically simple, allowing safe and stable handling of the colloids, due to reduced by-product formation, simpler starting materials and there is no need for a catalyst [7]. Three main steps contribute in laser ablation synthesis method and formation of nanoparticles from a target immersed in liquid. Only in a short period of time, typically about a few microseconds, all these steps take place and nanoparticles are synthesized as ablated particles go through the plume induced by laser ablation in liquid in which the temperature and pressure are very high, nanoparticles with new optical, electrical and mechanical properties can be expected to be fabricated [8-9]. Well crystallized nanoparticles can easily be obtained in one-step procedure without subsequent heat-treatments [10]. Nanoparticles are well known that optical and electrical properties are strongly dependent on the size and shape of nanoparticles. Therefore, control of size and shape is very important for tuning its properties over a wide range. Hence, from the fundamentals and practical aspects, studying the effects of synthesis parameters on the physical properties is very important and can lead to the size and shape selective applications [11-12].

Experimental

SnO₂ nanoparticles were produced by the laser ablation of a tin target of 99.8% purity from (Fluke co.) placed in a container glass containing 1.5 ml of methanol. The tin target was irradiated vertically by a Q-switched Nd:YAG laser pulses at 1064 nm. The morphology properties of nanoparticles suspension such as particle shape and size were identified also by atomic force microscopy (AFM) (CSPM-AA3000). The absorbance of the prepared solution was examined using a spectrophotometer (Lambda 750, Perkin Elmer). Chemical composition of SnO₂ has been measured by Fourier Transform Infrared (FTIR) (Burker Tensor 27). The electrical properties of SnO₂ NPs layers based device (Al/SnO₂ NPs/c-Si/Al) were studied for *I-V* and *C-V* measurements.

Results and discussion

Figure (1) Shows TEM images of colloidal SnO₂ NP_s at different laser energies. The average particles sizes of nanoparticles were calculated to have of 37 and 17 nm at laser energy 200 and 600 mJ respectively. The NPs in liquids have an almost perfect spherical

shape and shown in images agglomerated, some presented chains of welded particles. It also displays the size of particles dependency on laser energy.

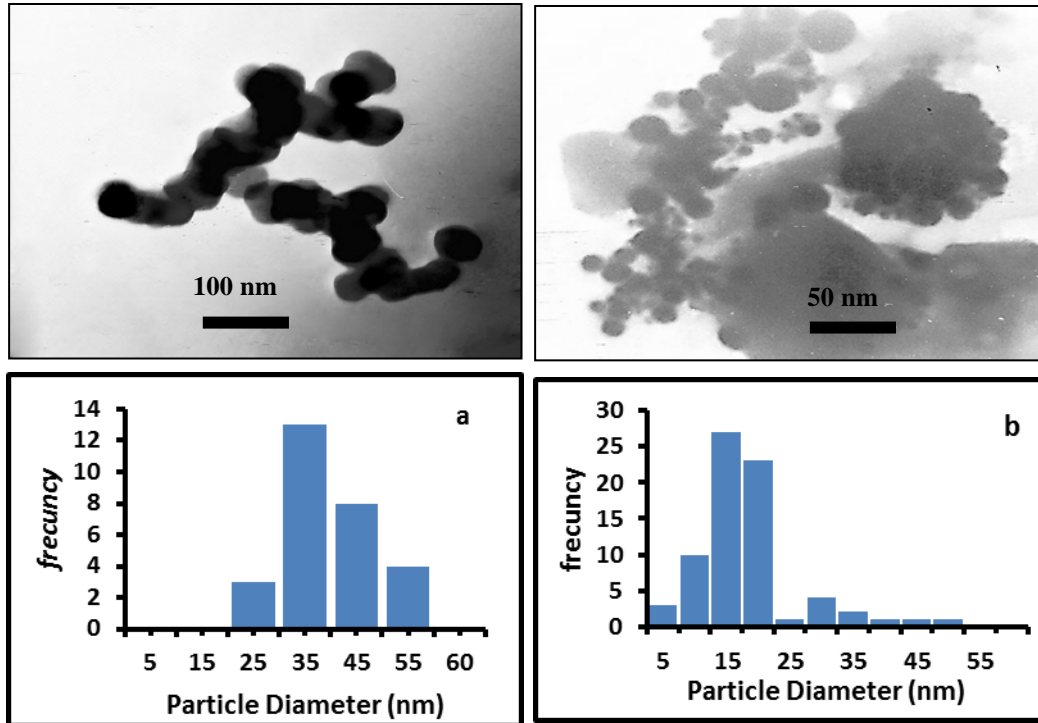


Figure (1): TEM micrographs of SnO₂ NPs prepared with pulse laser energy of (a) 200 mJ (b) 600 mJ

Figure (2) Shows the AFM images show that SnO₂ nanoparticles has semi-spherical shapes and from graphical (2D and 3D) we see that the number and particles distribution increases with increasing in number of pulses. From Figure (2) an increase in number of pulses, the size diameter of the prepared nanoparticles decreases. Actually, with increase in number of pulses, more number of nanoparticles is produced and these nanoparticles accumulate near the laser spot; when the number of produced nanoparticles becomes sufficiently large, they shield the incident laser radiation. Hence the value of the incident laser intensity reaching the solid target is decreased, which causes no further increase in the number of nanoparticles. However, further incidence of the laser light causes fragmentation of the nanoparticles produced in the earlier steps and leads to the reduction of size of the nanoparticles produced with longer values of laser pulses duration [13-14].

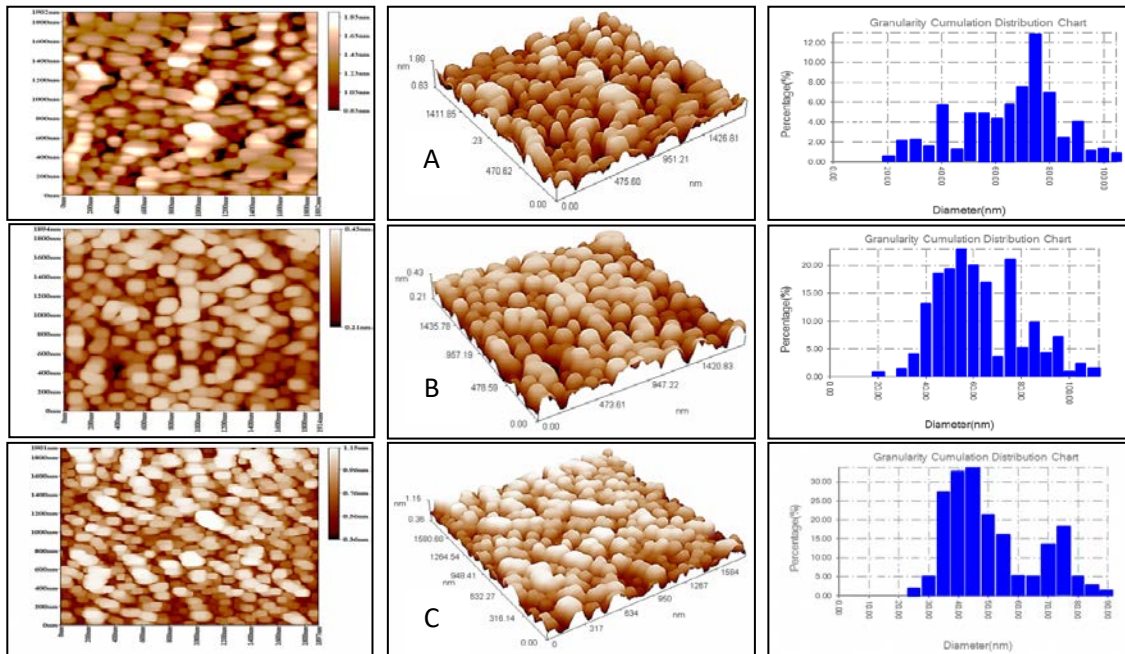


Figure (2): 2D and 3D AFM images of SnO₂NPs prepared with different number of pulses of (A) 60 (B) 90 and (C) 120 pulses.

Table (1): Results of The AFM images morphology characteristics with of SnO₂ NPs

Laser pulses	Avg. diameter (nm)	Ave. Roughness (nm)	RMS (nm)
60	70.56	0.203	0.246
90	57.21	0.0393	0.0467
120	40.74	0.153	0.181

Figure(3) Shows the FTIR spectrum of SnO₂NP suspensions, where we observed a broad peak centered at 3358 cm⁻¹ corresponding to O–H stretching, the appearance of sharp peaks at 3000-2800 cm⁻¹ region for C–H stretching. Also the same anti-symmetric vibrations of Sn–O are formed, the peak absorption of SnO₂NP suspension at 657 cm⁻¹.

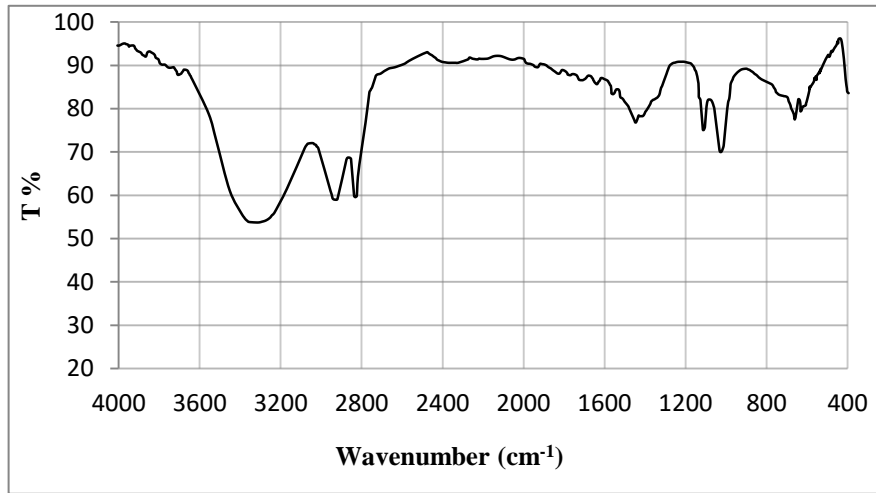
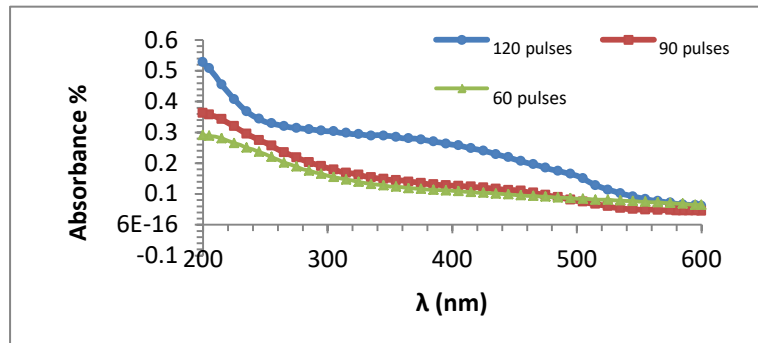


Figure (3): FTIR spectrum of SnO₂ NP suspensions in methanol at 600 mJ and No. of pulses 120.

Figure (4), presents an optical absorption spectra of the samples prepared in methanol solvent. When an increase in laser energy results in an increase in the absorbance spectra intensity, while the peak position remaining practically constant. This enhancement in intensity can be explained by the increase in the concentration of SnO₂ NPs formed in solution during the ablation process these results are confirms with other researches [15-17]. When increase in number of laser pulses Figure (4a) results in an increase in absorption peak intensity. It is clear that more nanoparticles could be generated in higher number of laser pulses. Actually, with increase in laser pulses, more number of nanoparticles is produced and these nanoparticles accumulate near the laser spot; when the number of produced nanoparticles becomes sufficiently large, they shield the incident laser radiation [18].



Figure(4): Optical absorption as a function of wavelength for SnO₂ NPs prepared at different number of pulses.

From Figure (5) and Table (2), give values of the energy band of all the prepared samples is higher than that of bulk SnO₂ (3.6 eV) and the band gap energy increases for the samples prepared with larger value of laser pulses. This attributed to the decreases in the particle size with increasing laser pulses. This behavior can be explained by the quantum confinement model [19].

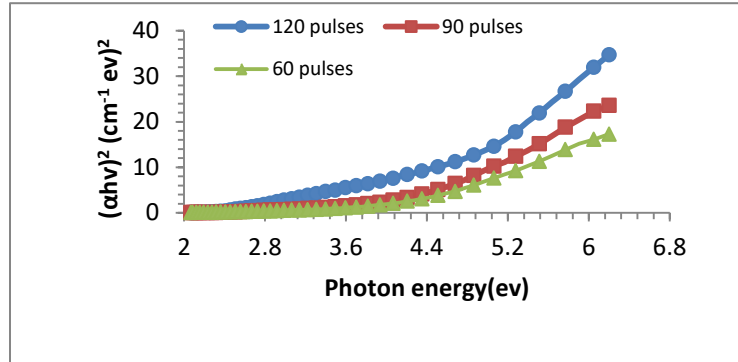


Figure (5): The $(\alpha h\nu)^2$ versus $h\nu$ plots for SnO₂ NPs prepared at different laser number of pulses

Table (2): Values of optical band gap as function of laser number pulses for SnO₂ NPs.

No. of pluses	Laser energy (mJ)	E _g (eV)
60	600	4.16
90		4.2
120		4.26

Figure (6) shows the forward bias current can be divided into two distinct regions; the first one represents recombination current while the second represents the tunneling current. At 0.3 volt , the forward current increases exponentially because the bias voltage exceeds the potential barrier. This bias voltage gives the electrons energy to overcome the barrier height and flow that is called diffusion current. The values of ideality factor for these devices is greater than unity equal to 5.758 which can be attributed to the recombination of electrons and holes in the depletion region as well as the tunneling effect depending on both sides of the heterojunction and on the presence of defect state

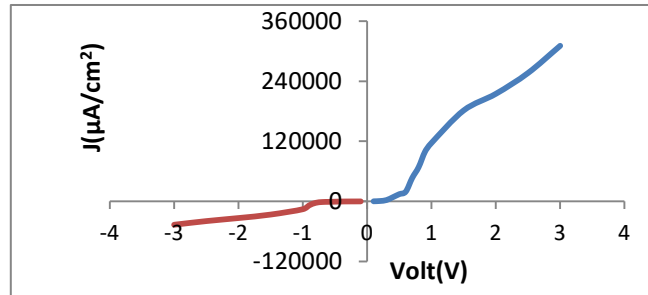


Figure (6): *J-V* characteristics under dark for SnO₂NPs/c-Si heterojunction at 600 mJ 120 pulse.

Figure (7) Shows *C-V* characteristics under reverse bias for Al/SnO₂/c-Si/Al at various laser energy at 600 mJ/pulse with 120 pulses. Notice that the capacitance is inversely proportional to the bias voltage for prepared samples, due to the expansion of depletion layer with the built-in potential. The depletion layer capacitance refers to the increment in charge per unit area to the incremental change of the applied voltage. This property gives an indication about the behavior of the charge transition from the donor to the acceptor region, which was found to be "abrupt" in one sample and this is confirmed when the relation between $1/C^2$ and reverse bias is a straight line. The built in potential V_{bi} can be distinguished from the plot of $1/C^2 = 0$ versus V obtained from the intersect of the $f(V)=1/C^2$ plot with x-axis.

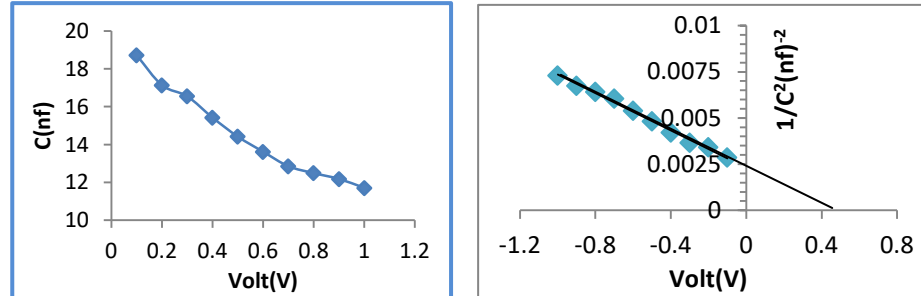


Figure (7): Dark *C-V* characteristics under reverse bias for Al/SnO₂/c-Si/Al sandwich structure at different laser energy.

Table (4): The value of effective charge carrier, width of depletion layer and built up potential of SnO₂ NPs/c-Si.

Laser energy (mJ)	No. of pulses	N_d (cm ⁻³)	W (μm)	V_{bi} (Volt)
600	120	5.34×10^{21}	8.7	0.48

Conclusions

SnO₂ nanoparticles are prepared by laser ablation in methanol from morphology properties show is spherical nanoparticles, the size and size distribution of which depends on the experimental conditions. From FTIR Anti-symmetric vibrations of Sn–O are formed, the peak absorption of SnO₂ NPs suspension at 657 cm⁻¹. It is found that the band gap energy of SnO₂ NPs is higher than that of bulk SnO₂ due to the decreases in the particle size according to the quantum confinement model.

The Al/SnO₂/c-Si/Al heterojunction has good linearity but with poor photovoltaic characteristics due to charge carriers recombination.

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